





Vectron's VT-704 Temperature Compensated Crystal Oscillator (TCXO) is a quartz stabilized, Clipped sine wave or CMOS output, analog temperature compensated oscillator, operating off a 2.5V to 3.3 volt supply in a hermetically sealed 7.0 x 5.0 mm ceramic package.

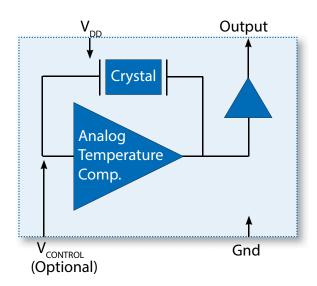
Features

- Clipped Sine Wave or CMOS Output
- 5.000 52.000MHz Output Frequency
- ±0.5ppm Temperature Stability
- Optional Frequency Tuning
- Fundamental Crystal Design
- · Gold over nickel contact pads
- Hermetically Sealed Ceramic SMD package
- Product is compliant to RoHS directive and fully compatible with lead free assembly

Applications

- Femto Cells
- Base Stations
- IP Networking
- Global Positioning Systems
- Point to Point Radio
- Manpack Radio
- Test and Measurement

Block Diagram



Specifications

Table 1. Electrical Performance, Clipped	d Sine Wave Op	otion			
Parameter	Symbol	Min.	Тур	Max	Units
Output Frequency ¹ , Ordering Option	f_{o}	5		52	MHz
Supply Voltage ³ , Ordering Option	V _{DD}	+2	.5, +2.8, +3.0, +3	3.3	V
Supply Current	I _{DD}			3.5	mA
Operating Temperature, Ordering Option	T _{OP}	0/55, -10/70, -	-20/70, -30/80, -	30/85, -40/85	°C
	Frequen	cy Stability			
Stability Over T _{OP} ⁴ , Ordering Option	F _{STAB}	±0.5, ±1.0, ±1.	.5 , ±2.0, ±2.5, ±	3.0, ±4.0, ±5.0	ppm
Frequency Tolerance ⁵	F _{TOL}			±2.0	ppm
Power Supply Stability, ±5%	F _{PWR}			±0.1	ppm
Load Stability, ±10%	F _{LOAD}			±0.2	ppm
Aging / 1st year	F_{AGE}			±1.0	ppm
Fr	equency Tuning ((EFC), Ordering O _l	otion		
Tuning Range ⁶	PR	±5.0	ppm		
Tuning Slope			Positive		
Control Voltage to reach Pull Range	V _c	0.5	1.5	2.5	V
Control Voltage Impedance		100			Kohm
RF Ou	tput (Clipped Sir	ne Wave), <i>Orderin</i> g	g Option		
Output Level High	V _o р-р	0.8			V
Output Load	C_{L}		10k 10pF		
Start Up Time	t _{su}			2	ms
	Phase	e Noise ⁷			
Phase Noise, 10.00MHz ⁷	0 _N				dBc/Hz
10Hz 100Hz			-96 -122		
100H2 1kHz			-122 -140		
10kHz			-148		
100kHz			-153		

^{1.} Refer to Table 8 for Standard Frequencies. Other Frequencies are available on request. Check with factory.

^{2.} Output DC-cut capacitor is optional.

^{3.} The VT-704 power supply pin (Pin4) should be filtered using a by-pass capacitor of 0.1uF for optimal performance.

^{4.} Referenced to the midpoint between minimum and maximum frequency value over Operating Temperature Range.

^{5.} Frequency measured at 25 °C, 1 hour after 2 IR reflows.

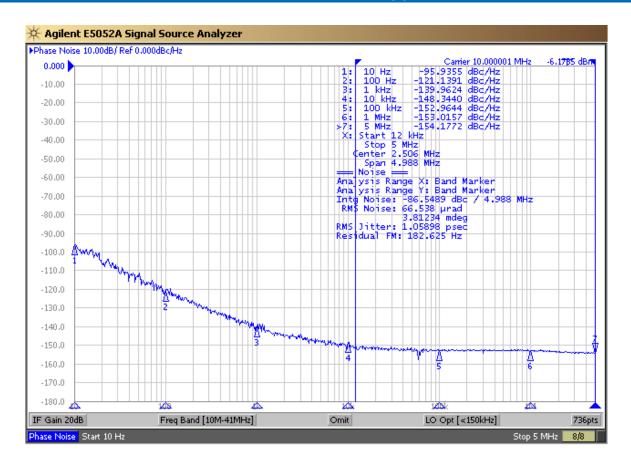
^{6.} Referenced to Mid Control Voltage

^{7.} Measured at ambient temperature using Agilent E5052B Signal Source Analyzer.

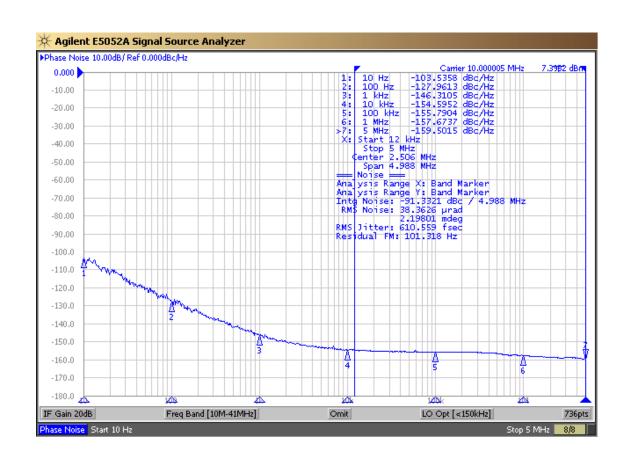
Table 2. Electrical Performance, CMOS	Option						
Parameter	Symbol	Min.	Тур	Max	Units		
Output Frequency ¹ , Ordering Option	f_{o}	5		52	MHz		
Supply Voltage ³ , Ordering Option	$V_{_{ m DD}}$	+2	.5, +2.8, +3.0, +3	3.3	V		
Supply Current	I _{DD}			6.0	mA		
Operating Temperature, Ordering Option	T _{OP}	0/55, -10/70, -	-20/70, -30/80, -	30/85, -40/85	°C		
	Frequen	cy Stability					
Stability Over T _{OP} ⁴ , Ordering Option	F _{STAB}	±0.5, ±1.0, ±1.	5 , ±2.0, ±2.5, ±	3.0, ±4.0, ±5.0	ppm		
Frequency Tolerance ⁵	F _{TOL}			±2.0	ppm		
Power Supply Stability, ±5%	F _{PWR}			±0.1	ppm		
Load Stability, ±10%	F _{LOAD}			±0.2	ppm		
Aging / 1st year	F _{AGE}			±1.0	ppm		
Frequency Tuning (EFC), Ordering Option							
Tuning Range ⁶	PR	±5.0	ppm				
Tuning Slope		Positive					
Control Voltage to reach Pull Range	V _c	0.5	1.5	2.5	V		
Control Voltage Impedance		100			Kohm		
	RF Output (CMO	S), Ordering Option	on				
Output Level High Output Level Low	V _{OH} V _{OL}	0.9*V _{DD}		0.1*V _{DD}	V		
Output Load	C _L			15	pF		
Duty Cycle		45		55	%		
Start Up Time	t _{su}			2	ms		
Rise & Fall Times				4	ns		
	Phase	e Noise ⁷					
Phase Noise, 10.00MHz ⁷ 10Hz 100Hz 1kHz 10kHz 10kHz	0 _N		-98 -129 -145 -153 -156		dBc/Hz		

- 1. Refer to Table 8 for Standard Frequencies. Other Frequencies are available on request. Check with factory.
- 2. Output DC-cut capacitor is optional.
- 3. The VT-704 power supply pin (Pin4) should be filtered using a by-pass capacitor of 0.1uF for optimal performance.
- 4. Referenced to the midpoint between minimum and maximum frequency value over Operating Temperature Range.
- 5. Frequency measured at 25 °C, 1 hour after 2 IR reflows.
- 6. Referenced to Mid Control Voltage.
- 7. Measured at ambient temperature using Agilent E5052B Signal Source Analyzer

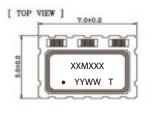
Phase Noise Performance for 10MHz Clipped Sine Wave

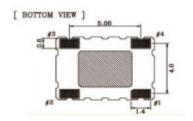


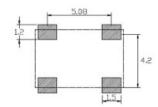
Phase Noise Performance for 10MHz CMOS



Package Outline Drawing & Pad Layout









Dimensions in mm

Marking Information

XXMXX - Frequency (Example: 10M000)

YY - Year of Manufacture

WW - Week of the Year

T - Manufacturing Location

- Pin 1 Indicator

Table 3. Pinout								
Pin#	Symbol	Function						
1	Vc or NC	Vc or NC TCXO Control Voltage or No Connect						
2	GND	GND Ground						
3	OUT	RF Output						
4	V _{DD}	Supply Voltage						

Note:

0.1uF capacitor is a by-pass power supply filter capacitor placed between Pin4 (Vdd) and Ground for optimal performance.

VCXO Function

VCXO Feature: The VT-704 is supplied with a VCXO function for applications were it will be used in a PLL, or the output frequency needs fine tune or calibration adjustments. This is a high impedance input, 100kOhm, and can be driven with an op-amp or terminated with adjustable resistors etc. **Pin1 should not be left floating on the VCXO optional device.**

Maximum Ratings

Absolute Maximum Ratings and Handling Precautions

Stresses in excess of the absolute maximum ratings can permanently damage the device. Functional operation is not implied or any other excess of conditions represented in the operational sections of this data sheet. Exposure to absolute maximum ratings for extended periods may adversely affect device reliability.

Although ESD protection circuitry has been designed into the VT-704, proper precautions should be taken when handling and mounting, VI employs a Human Body Model and Charged Device Model for ESD susceptibility testing and design evaluation. ESD thresholds are dependent on the circuit parameters used to define the model. Although no industry standard has been adopted for

the CDM a standard resistance of 1.5kOhms and capacitance of 100pF is widely used and therefor can be used for comparison purposes.

Table 4. Maximum Ratings			
Parameter	Symbol	Rating	Unit
Storage Temperature	T _{STORE}	-55/125	°C
Supply Voltage	$V_{_{ m DD}}$	-0.6/6	V
Control Voltage	V_{c}	-0.6/V _{DD} +0.6	V
Enable/Disable Voltage	E/D	-0.6/V _{DD} +0.6	V
ESD, Human Body Model		1500	V
ESD, Charged Device Model		1000	V

Reliability

Table 5. Environmental Compliance					
Parameter	Condition				
Mechanical Shock	MIL-STD-883 Method 2002				
Mechanical Vibration	MIL-STD-883 Method 2007				
Temperature Cycle	MIL-STD-883 Method 1010				
Solderability	MIL-STD-883 Method 2003				
Fine and Gross Leak	MIL-STD-883 Method 1014				
Resistance to Solvents	MIL-STD-883 Method 2015				
Moisture Sensitivity Level	MSL1				
Contact Pads	Gold over Nickel				

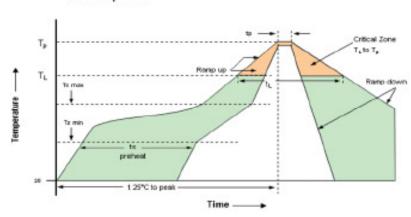
IR Reflow

Suggested IR Profile

Devices are built using lead free epoxy and can be subjected to standard lead free IR reflow conditions shown in Table 6. Contact pads are gold over nickel and lower maximum temperatures can also be used, such as 220°C.

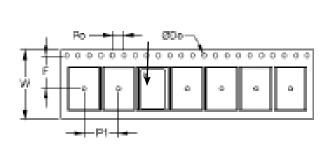
Table 6. Reflow Profile		
Parameter	Symbol	Value
PreHeat Time Ts-min Ts-max	t _s	200 sec Max 150°C 200°C
Ramp Up	R_{UP}	3°C/sec Max
Time above 217C	t _L	150 sec Max
Time to Peak Temperature	t _{25C to peak}	480 sec Max
Time at 260C	t _p	30 sec Max
Time at 240C	t _{P2}	60 sec Max
Ramp down	$R_{_{\mathrm{DN}}}$	6°C/sec Max

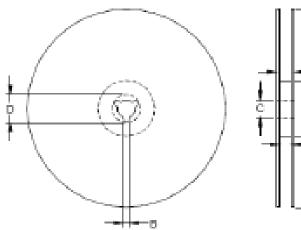
Solderprofile:

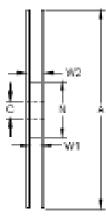


Tape & Reel

Table 7.	Tape and	Reel Info	rmation									
Tape Dimensions (mm) Reel Dimensions (mn					s (mm)							
W	F	Do	Ро	P1	Α	В	С	D	N	W1	W2	#/Reel
16	7.5	1.5	4	8	180	1.5	13	20.2	60	16.4	20.4	1000



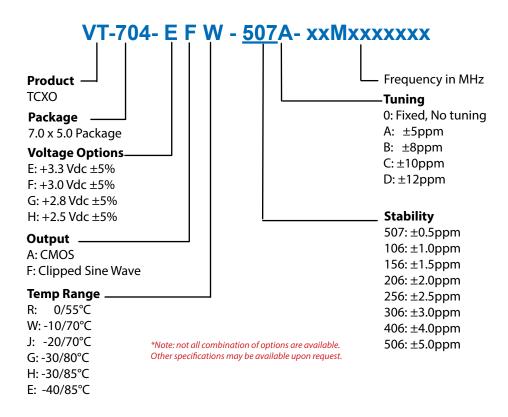




Ordering Information

Table 8. Sta	ındard Frequ	iencies (MHz	2)						
8.000	8.192	10.000	12.800	16.000	16.384	19.200	19.440	25.000	26.000
40.000									

Note: Other Frequencies are available on request.



Example: VT-704-EFW-507A-12M8000000

* Add **_SNPBDIP** for tin lead solder dip Example: VT-704-EFW-507A-12M8000000 SNPBDIP

Revision History

Revision Date	Approved	Description		
May 4, 2015	VN	Rev 0.1: VT-704 Product Preliminary Datasheet - Internal Verification		
May11, 2015	VN	Rev 0.2: Preliminary Datasheet Website (Product Launch)		
June 16, 2015	VN	Rev 0.3: Added temperature code "G" for -30/80 °C operating temperature range		
June 14, 2016	VN	Rev 0.4: Removed "Preliminary".		
August 10, 2018	FB	Updated logo and contact information,, added "SNPBDIP" ordering option		



Microsemi Headquarters

microsemi Headquarters
One Enterprise, Aliso Vielo, CA 92656 USA
Within the USA: +1 (800) 713-4113
Outside the USA: +1 (949) 380-6100
Sales: +1 (949) 380-6136
Fax: +1 (949) 215-4996 email: sales.support@microsemi.com www microsemi com

Microsemi, a wholly owned subsidiary of Microchip Technology Inc. (Nasdaq: MCHP), offers a comprehensive portfolio of semiconductor and system solutions for aerospace & defense, communications, data center and industrial markets. Products include high-performance and radiation-hardened analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs, power management products; timing and synchronization devices and precise time solutions, setting the worlds standard for time; voice processing devices; RF solutions; discrete components; enterprise storage and communication solutions, security technologies and scalable anti-tamper products; Ethernet solutions; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services. Learn more at www.microsemi.com

Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, alone and together with, or installed in, any end-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the Buyer's responsibility to independently determine suitability of any post and verify the same. The information provided by Microsemi hereunder is provided "as is, where is" and with all faults, and the entire risk associated with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other IP injustic, whether with regard to such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party and microsemi reserves the right to make any changes to the information in this document or to any products and services at any time without notice.

©2018 Microsemi, a wholly owned subsidiary of Microchip Technology Inc. All rights reserved. Microsemi and the Microsemi logo are registered trademarks of Microsemi Corporation. All other trademarks and service marks are the property of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for TCXO Oscillators category:

Click to view products by Vectron manufacturer:

Other Similar products are found below:

SiT5000AI-3D-33E0-10.000000X THD3031035LK280005-10.0M CVT32-10.000 SIT5356AI-FQ-33E0-25.000000X

XTCLH25M000THJA0P0 LFTCXO075793Cutt LFTCXO077229Cutt LFPTXO000002Bulk LFTCXO077228Cutt LFTCXO077230Cutt

LFTCXO075792Cutt LFPTXO000001Bulk LFTCXO063711BULK LFTCXO063713BULK LFTCXO063715BULK LFTCXO063780BULK

LFTCXO070027Cutt LFTCXO070028Cutt LFTCXO070033Cutt LFTCXO070037Cutt LFTCXO070179Cutt LFTCXO070180Cutt

LFTCXO007009BULK DS32KHZST&R XNCLH20M000CHJA3P0 XNCLH25M000THJA0P0 XNCLH30M720THJA1P0

XTCLH16M384THJA2P0 XTCLH20M000CHJA0P0 XTCLH30M720THJA0P0 NT2016SA-26.000000MHZ-NBG2 SIT1552AI-JE-DCC-32.768E SIT1566AI-JE-18E-32.768E SIT1552AI-JF-DCC-32.768D SIT1566AI-JV-18E-32.768E SIT5000AICGE-33N0-25.000000X

SiT5021AI-2BE-33VQ200.000000X SiT5155AI-FK-33E0-10.000000X SiT5155AI-FK-33VT-10.000000X SiT5156AI-FK-33E0-25.000000X

SiT5157AI-FK-33N0-100.000000X 7Q16300001 7L-38.400MDG-T 7Z-26.000MBG-T LFTCXO075792 LFTCXO075797

LFPTXO000009Bulk LFPTXO000316Bulk SiT5000AICGE-33E0-25.000000X SiT1568AI-JE-DCC-32.768E